

Silicon PNP Epitaxial Planar Transistor (Complement to type 2SC3263)

Application : Audio and General Purpose

Absolute maximum ratings (Ta=25°C)

Symbol	Ratings	Unit
V _{CB0}	-230	V
V _{CE0}	-230	V
V _{EBO}	-5	V
I _C	-15	A
I _B	-4	A
P _C	130(T _C =25°C)	W
T _J	150	°C
T _{stg}	-55 to +150	°C

Electrical Characteristics (Ta=25°C)

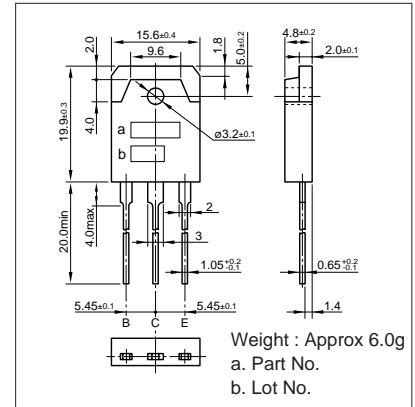
Symbol	Conditions	Ratings	Unit
I _{CB0}	V _{CB} =-230V	-100max	μA
I _{EBO}	V _{EB} =-5V	-100max	μA
V(BR) _{CEO}	I _C =-25mA	-230min	V
h _{FE}	V _{CE} =-4V, I _C =-5A	50min*	
V _{CE(sat)}	I _C =-5A, I _B =-0.5A	-2.0max	V
f _r	V _{CE} =-12V, I _E =2A	35typ	MHz
COB	V _{CB} =-10V, f=1MHz	500typ	pF

*h_{FE} Rank \bar{O} (50to100), Y(70to140)

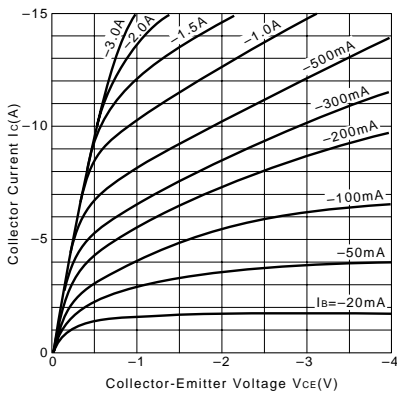
Typical Switching Characteristics (Common Emitter)

V _{CC} (V)	R _L (Ω)	I _C (A)	V _{BB1} (V)	V _{BB2} (V)	I _{B1} (mA)	I _{B2} (mA)	t _{on} (μs)	t _{stg} (μs)	t _f (μs)
-60	12	-5	-10	5	-500	500	0.35typ	1.50typ	0.30typ

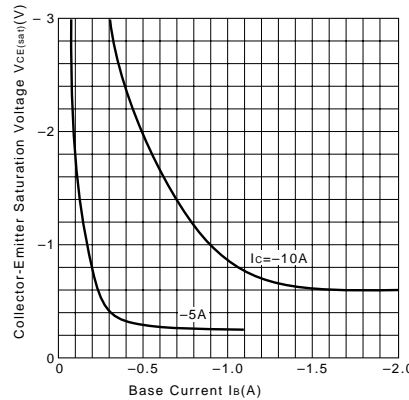
External Dimensions MT-100(TO3P)



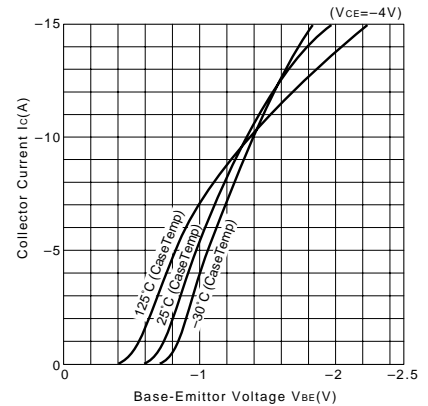
I_C-V_{CE} Characteristics (Typical)



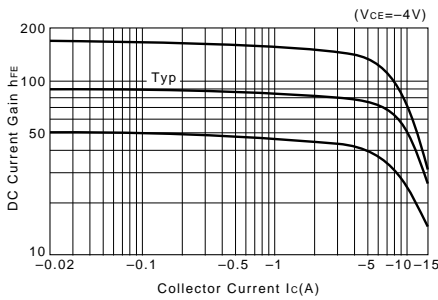
V_{CE(sat)}-I_B Characteristics (Typical)



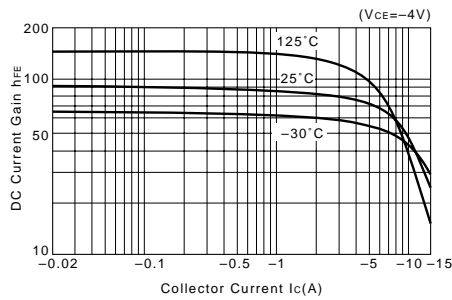
I_C-V_{BE} Temperature Characteristics (Typical)



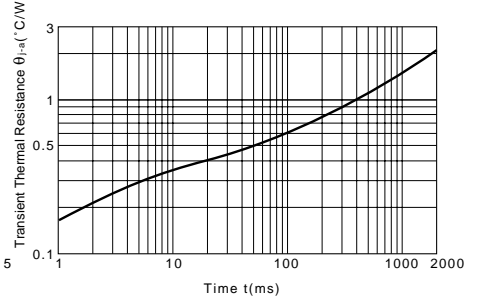
h_{FE}-I_C Characteristics (Typical)



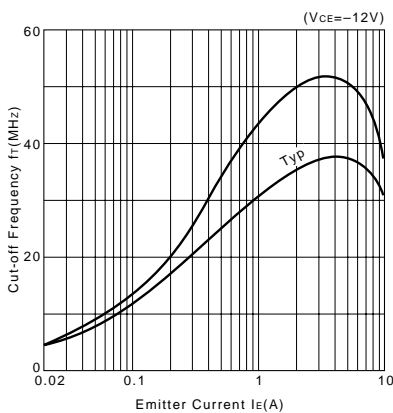
h_{FE}-I_C Temperature Characteristics (Typical)



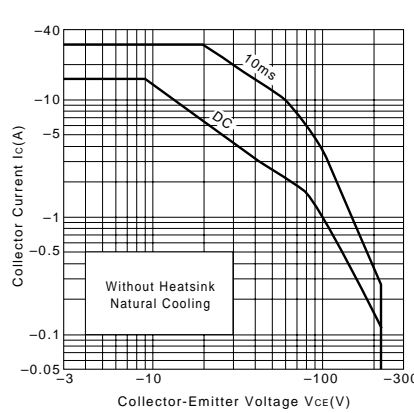
θ_{j-a}-t Characteristics



f_T-I_E Characteristics (Typical)



Safe Operating Area (Single Pulse)



P_C-T_a Derating

